

3V~5.5V、1チャネルRS-232 1Mbit/s ライン・ドライバ/レシーバ、 ±15kV IEC ESD 保護機能搭載

1 特長

- RS-232 ピンの ESD 保護
 - ±15kV 人体モデル (HBM)
 - ±8kV IEC 61000-4-2 接触放電
 - ±15kV IEC 61000-4-2 エアギャップ放電
- 3V~5.5V の V_{CC} 電源で動作
- 最大 1Mbit/s で動作
- 低スタンバイ電流 ...標準値 1μA
- 外付けコンデンサ ...4 × 0.1μF
- 3.3V 電源で 5V ロジック入力を受容
- ±15kV (人体モデル (HBM)) を超える RS-232 バス・ピン ESD 保護
- 自動パワー・ダウン機能により、ドライバを自動的にディスエーブルすることで電力を節約

2 アプリケーション

- 産業用 PC
- 有線ネットワーク
- データ・センターおよびエンタープライズ・コンピューティング
- バッテリー駆動システム
- PDA
- ノートブック PC
- ノート PC
- パームトップ PC
- ハンドヘルド機器

3 概要

SN65C3221E と SN75C3221E は 1 つのライン・ドライバ、1 つのライン・レシーバ、1 つのデュアル・チャージ・ポンプ回路で構成されており、±15kV のピン間 (シリアル・ポート接続ピン、GND を含む) IEC ESD 保護機能を備えています。これらのデバイスは、非同期通信コントローラとシリアルポート・コネクタの間の電氣的インターフェイスとして機能します。チャージ・ポンプと 4 つの小さな外付けコンデンサにより、3V~5.5V の単一電源で動作できます。

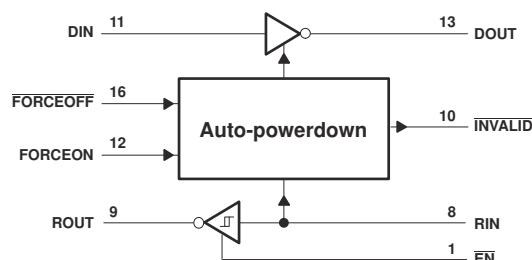
これらのデバイスは最大 1Mbit/s のデータ信号速度、24V/μs~150V/μs のドライバ出力スlewレートで動作します。

シリアル・ポートが使われていない際のパワー・マネージメントを柔軟に制御できます。FORCEON が LOW かつ FORCEOFF が HIGH の場合、自動パワー・ダウン機能が動作します。この動作モード中、デバイスがレシーバ入力で有効な RS-232 信号を検出しない場合、ドライバ出力はディスエーブルになります。FORCEOFF を LOW に設定しかつ EN を HIGH に設定すると、ドライバとレシーバはどちらもシャットダウンされ、消費電流は 1μA に減少します。シリアル・ポートを切り離れた場合、またはペリフェラル・ドライバをオフにした場合、自動パワー・ダウン状態になります。FORCEON と FORCEOFF を HIGH にすると、自動パワー・ダウンを無効にできます。自動パワー・ダウンが有効な場合、レシーバの入力に有効な信号が印加されると、デバイスは自動的にアクティブになります。INVALID 出力は、レシーバの入力に RS-232 信号が存在するかどうかをユーザーに通知します。INVALID は、レシーバの入力電圧が 2.7V を上回っている場合、-2.7V を下回っている場合、-0.3V と 0.3V の間にあった期間が 30μs 未満である場合のいずれかの場合、HIGH (有効データ) になります。INVALID は、レシーバの入力電圧が 30μs を超える期間 -0.3V と 0.3V の間にある場合、LOW (無効データ) になります。レシーバの入力レベルについては、図 8-5 を参照してください。

製品情報

部品番号	パッケージ ⁽¹⁾	本体サイズ (公称)
SNx5C3221E	SSOP (DB) 16	6.20mm × 5.30mm
	TSSOP (DW) 16	10.3mm × 7.50mm

- (1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。



論理図 (正論理)



Table of Contents

1 特長	1	7.11 Auto-powerdown Section: Electrical Characteristics.....	9
2 アプリケーション	1	7.12 Switching Characteristics: Auto-powerdown.....	9
3 概要	1	8 Parameter Measurement Information	10
4 Revision History	2	9 Detailed Description	13
5 Device Comparison Table	3	9.1 Device Functional Modes.....	13
6 Pin Configuration and Functions	4	10 Application and Implementation	14
7 Specifications	5	10.1 Application Information.....	14
7.1 Absolute Maximum Ratings.....	5	11 Device and Documentation Support	15
7.2 ESD Ratings.....	5	11.1 Receiving Notification of Documentation Updates..	15
7.3 ESD Ratings - IEC Specifications.....	5	11.2 サポート・リソース.....	15
7.4 Recommended Operating Conditions.....	6	11.3 Trademarks.....	15
7.5 Thermal Information.....	6	11.4 Electrostatic Discharge Caution.....	15
7.6 Electrical Characteristics.....	7	11.5 Glossary.....	15
7.7 Driver Section: Electrical Characteristics.....	7	12 Mechanical, Packaging, and Orderable Information	15
7.8 Switching Characteristics: Driver.....	7		
7.9 Receiver Section: Electrical Characteristics.....	8		
7.10 Switching Characteristics: Receiver.....	8		

4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision B (April 2009) to Revision C (July 2021)	Page
• 「アプリケーション」の一覧を変更.....	1
• 「注文情報」表を削除.....	1
• 製品情報の表を追加.....	1
• Added the <i>Pin Configuration and Functions</i>	4
• Removed the thermal information from <i>Absolute Maximum Rating</i> stable and moved the thermal information to its own table.....	5
• Added a table note for PW package of SN65C3221E regarding the minimum capacitance in <i>ESD Ratings - IEC Specifications</i> table.....	5
• Changed thermal information for PW package of SN65C3221E. Added additional thermal information for other packages.....	6
• Added the <i>Detailed Description</i> section.....	13

5 Device Comparison Table

表 5-1. 1-Mbit/s RS-232 Parts

PART NO.	TEMPERATURE RANGE	DRIVER NO.	RECEIVER NO.	ESD	SUPPLY V _{CC} (V)	FEATURE	PIN/PACKAGE
SN65C3221E	-40°C to 85°C	1	1	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto powerdown	16-pin SOIC, SSOP, TSSOP
SN65C3232E		2	2	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
MAX3227I		1	1	±8-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto powerdown plus, ready signal	16-pin SSOP
SN65C3221		1	1	±15-kV HBM	3.3 or 5	Auto powerdown	16-pin SOIC, SSOP, TSSOP
SN65C3223		2	2	±15-kV HBM	3.3 or 5	Auto powerdown, enable signal	20-pin SOIC, SSOP, TSSOP
SN65C3222		2	2	±15-kV HBM	3.3 or 5	Enable, powerdown signal	20-pin SOIC, SSOP, TSSOP
SN65C3232		2	2	±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
SN65C3238		5	3	±15-kV HBM	3.3 or 5	Auto powerdown plus	28-pin SOIC, SSOP, TSSOP
SN65C3243		3	5	±15-kV HBM	3.3 or 5	Auto powerdown	28-pin SOIC, SSOP, TSSOP
SN75C3221E	0°C to 70°C	1	1	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto powerdown	16-pin SOIC, SSOP, TSSOP
SN75C3232E		2	2	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
MAX3227C		1	1	±8-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto powerdown plus, ready signal	16-pin SSOP
SN75C3221		1	1	±15-kV HBM	3.3 or 5	Auto powerdown	16-pin SOIC, SSOP, TSSOP
SN75C3223		2	2	±15-kV HBM	3.5 or 5	Auto powerdown, enable signal	20-pin SOIC, SSOP, TSSOP
SN75C3222		2	2	±15-kV HBM	3.3 or 5	Enable, powerdown signal	20-pin SOIC, SSOP, TSSOP
SN75C3232		2	2	±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
SN75C3238		5	3	±15-kV HBM	3.3 or 5	Auto powerdown plus	28-pin SOIC, SSOP, TSSOP
SN75C3243		3	5	±15-kV HBM	3.3 or 5	Auto powerdown	28-pin SOIC, SSOP, TSSOP

6 Pin Configuration and Functions

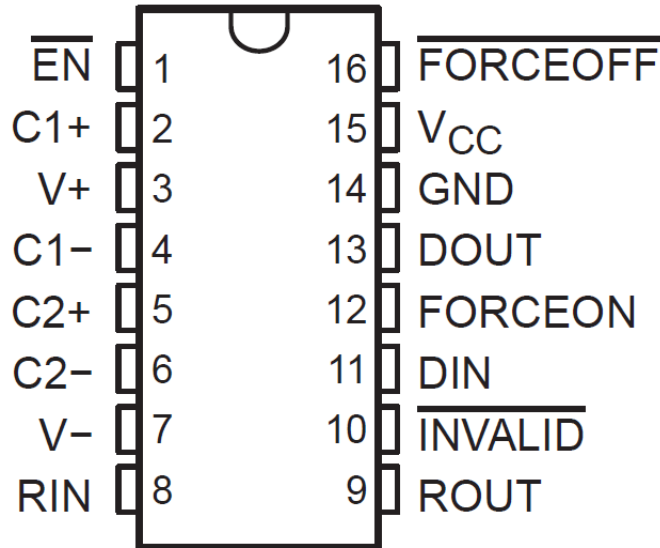


图 6-1. DB or PW Package
Top View

表 6-1. Pin Configurations

PIN		I/O	DESCRIPTION
NAME	NO		
EN	1	I	Low input enables receiver ROUT output. High input sets ROUT to high impedance.
C1+	2	—	Positive terminals of the voltage-doubler charge-pump capacitors
V+	3	O	5.5-V supply generated by the charge pump
C1-	4	—	Negative terminals of the voltage-doubler charge-pump capacitors
C2+	5	—	Positive terminals of the voltage-doubler charge-pump capacitors
C2-	6	—	Negative terminals of the voltage-doubler charge-pump capacitors
V-	7	O	-5.5-V supply generated by the charge pump
RIN	8	I	RS-232 receiver input
ROUT	9	O	Receiver output
INVALID	10	O	Invalid output pin. Output low when all RIN inputs are unpowered.
DIN	11	I	Driver input
FORCEON	12	I	Automatic power-down control input
DOUT	13	O	RS-232 driver output
GND	14	—	Ground
V _{CC}	15	—	3-V to 5.5-V supply voltage
FORCEOFF	16	I	Automatic power-down control input

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾	-0.3	6	V
V+	Positive output supply voltage range ⁽²⁾	-0.3	7	V
V-	Negative output supply voltage range ⁽²⁾	0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾		13	V
V _I	Input voltage range	Driver (FORCEOFF, FORCEON, EN)		V
		Receiver		
V _O	Output voltage range	Driver		V
		Receiver (INVALID)		
T _J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network GND.

7.2 ESD Ratings

			VALUE	UNIT	
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	DOUT, RIN	±15000	V
			All other pins	±3000	
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾		±1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 ESD Ratings - IEC Specifications

			VALUE	UNIT	
V _(ESD)	Electrostatic discharge	IEC 61000-4-2 Contact Discharge ⁽¹⁾	RIN and DOUT pins only	±8000	V
		IEC 61000-4-2 Air Discharge ⁽¹⁾	RIN and DOUT pins only	±15000	

- (1) For the PW package of SN65C3221E only, a minimum of 1-μF capacitor is required between VCC and GND to meet the specified IEC-ESD level.

7.4 Recommended Operating Conditions

See [10-1](#). see ⁽¹⁾

			MIN	NOM	MAX	UNIT
Supply voltage		V _{CC} = 3.3 V	3	3.3	3.6	V
		V _{CC} = 5 V	4.5	5	5.5	
V _{IH}	Driver and control high-level input voltage	DIN, FORCEOFF, FORCEON, EN	V _{CC} = 3.3 V	2		V
			V _{CC} = 5 V	2.4		
V _{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON, EN			0.8	V
V _I	Driver and control input voltage	DIN, FORCEOFF, FORCEON	0		5.5	V
V _I	Receiver input voltage		-25		25	V
T _A	Operating free-air temperature	SN65C3221E	-40		85	°C
		SN75C3221E	0		70	

(1) Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

7.5 Thermal Information

THERMAL METRIC ¹		SN65C3221E		SN75C3221E		UNIT
		PW (TSSOP)	DB (SSOP)	PW (TSSOP)	DB (SSOP)	
		16 PINS	16 PINS	16 PINS	16 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	110.9	82	108	82	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	41.7	45.7	41.1	45.7	°C/W
R _{θJB}	Junction-to-board thermal resistance	57.2	44.4	51.4	44.4	°C/W
ψ _{JT}	Junction-to-top characterization parameter	4.2	11.0	3.9	11.0	°C/W
ψ _{JB}	Junction-to-board characterization parameter	56.6	43.8	50.9	43.8	°C/W

7.6 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [10-1](#))

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT
I_I	Input leakage current	FORCEOFF, FORCEON, EN		±0.01	±1	μA
I_{CC}	Supply current ($T_A = 25^\circ\text{C}$)	Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V_{CC}	0.3	1	mA
		Powered off	No load, FORCEOFF at GND	1	10	μA
		Auto-powerdown enabled	No load, FORCEOFF at V_{CC} , FORCEON at GND, All RIN are open or grounded	1	10	

- (1) Test conditions are C1–C4 = 0.1 μF at $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$; C1 = 0.047 μF, C2–C4 = 0.33 μF at $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$.
(2) All typical values are at $V_{CC} = 3.3\text{ V}$ or $V_{CC} = 5\text{ V}$, and $T_A = 25^\circ\text{C}$.

7.7 Driver Section: Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [10-1](#))

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3\text{ k}\Omega$ to GND, DIN = GND	5	5.4		V
V_{OL}	Low-level output voltage	DOUT at $R_L = 3\text{ k}\Omega$ to GND, DIN = V_{CC}	–5	–5.4		V
I_{IH}	High-level input current	$V_I = V_{CC}$		±0.01	±1	μA
I_{IL}	Low-level input current	V_I at GND		±0.01	±1	μA
I_{OS}	Short-circuit output current ⁽³⁾	$V_{CC} = 3.6\text{ V}$, $V_O = 0\text{ V}$		±35	±60	mA
		$V_{CC} = 5.5\text{ V}$, $V_O = 0\text{ V}$		±35	±90	
r_o	Output resistance	V_{CC} , $V+$, and $V- = 0\text{ V}$, $V_O = \pm 2\text{ V}$	300	10M		Ω
I_{off}	Output leakage current	FORCEOFF = GND	$V_O = \pm 12\text{ V}$, $V_{CC} = 3\text{ V to } 3.6\text{ V}$		±25	μA
			$V_O = \pm 10\text{ V}$, $V_{CC} = 4.5\text{ V to } 5.5\text{ V}$		±25	

- (1) Test conditions are C1–C4 = 0.1 μF at $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$; C1 = 0.047 μF, C2–C4 = 0.33 μF at $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$.
(2) All typical values are at $V_{CC} = 3.3\text{ V}$ or $V_{CC} = 5\text{ V}$, and $T_A = 25^\circ\text{C}$.
(3) Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

7.8 Switching Characteristics: Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [10-1](#))

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT
Maximum data rate (see 8-1)	$R_L = 3\text{ k}\Omega$	$C_L = 1000\text{ pF}$		250		kbit/s
		$C_L = 250\text{ pF}$, $V_{CC} = 3\text{ V to } 4.5\text{ V}$		1000		
		$C_L = 1000\text{ pF}$, $V_{CC} = 4.5\text{ V to } 5.5\text{ V}$		1000		
$t_{sk(p)}$	Pulse skew ⁽³⁾	$C_L = 150\text{ pF to } 2500\text{ pF}$, $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, See 8-2		100		ns
SR(tr)	Slew rate, transition region (see 8-1)	$V_{CC} = 3.3\text{ V}$, $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, $C_L = 150\text{ pF to } 1000\text{ pF}$	18		150	V/μs

- (1) Test conditions are C1–C4 = 0.1 μF at $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$; C1 = 0.047 μF, C2–C4 = 0.33 μF at $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$.
(2) All typical values are at $V_{CC} = 3.3\text{ V}$ or $V_{CC} = 5\text{ V}$, and $T_A = 25^\circ\text{C}$.
(3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

7.9 Receiver Section: Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [10-1](#))

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT
V _{OH}	High-level output voltage	I _{OH} = -1 mA	V _{CC} - 0.6 V	V _{CC} - 0.1 V		V
V _{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 3.3 V		1.6	2.4	V
		V _{CC} = 5 V		1.9	2.4	
V _{IT-}	Negative-going input threshold voltage	V _{CC} = 3.3 V	0.6	1.1		V
		V _{CC} = 5 V	0.8	1.4		
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.5		V
I _{off}	Output leakage current	FORCEOFF = 0 V		±0.05	±10	µA
r _i	Input resistance	V _i = ±3 V to ±25 V	3	5	7	kΩ

(1) Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

7.10 Switching Characteristics: Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [10-1](#))

PARAMETER		TEST CONDITIONS ⁽¹⁾	TYP ⁽²⁾	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, See 8-3	150	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See 8-3	150	ns
t _{en}	Output enable time	C _L = 150 pF, R _L = 3 kΩ, See 8-4	200	ns
t _{dis}	Output disable time	C _L = 150 pF, R _L = 3 kΩ, See 8-4	200	ns
t _{sk(p)}	Pulse skew ⁽³⁾	See 8-3	50	ns

(1) Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

(3) Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

7.11 Auto-powerdown Section: Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [8-5](#))

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
$V_{T+(valid)}$	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V_{CC}		2.7	V
$V_{T-(valid)}$	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V_{CC}	-2.7		V
$V_{T(invalid)}$	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, FORCEOFF = V_{CC}	-0.3	0.3	V
V_{OH}	INVALID high-level output voltage	$I_{OH} = -1$ mA, FORCEON = GND, FORCEOFF = V_{CC}	$V_{CC} - 0.6$		V
V_{OL}	INVALID low-level output voltage	$I_{OL} = 1.6$ mA, FORCEON = GND, FORCEOFF = V_{CC}		0.4	V

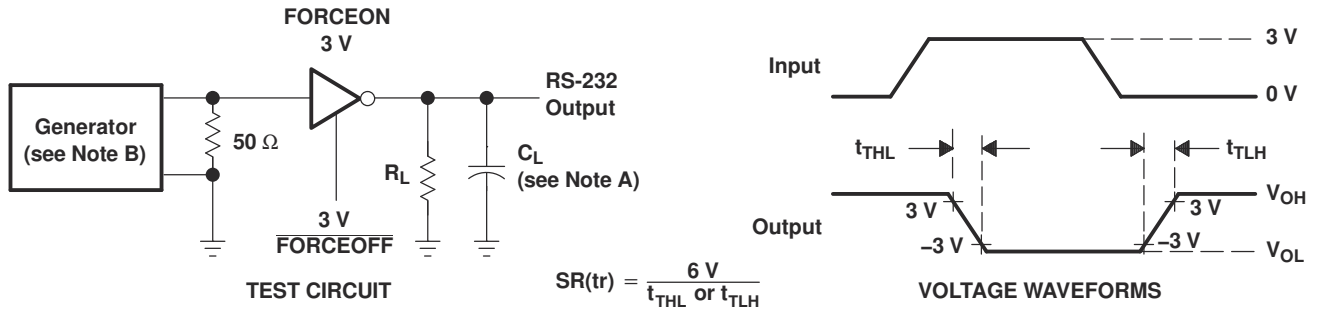
7.12 Switching Characteristics: Auto-powerdown

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [8-5](#))

PARAMETER		TYP ⁽¹⁾	UNIT
t_{valid}	Propagation delay time, low- to high-level output	1	μ s
$t_{invalid}$	Propagation delay time, high- to low-level output	30	μ s
t_{en}	Supply enable time	100	μ s

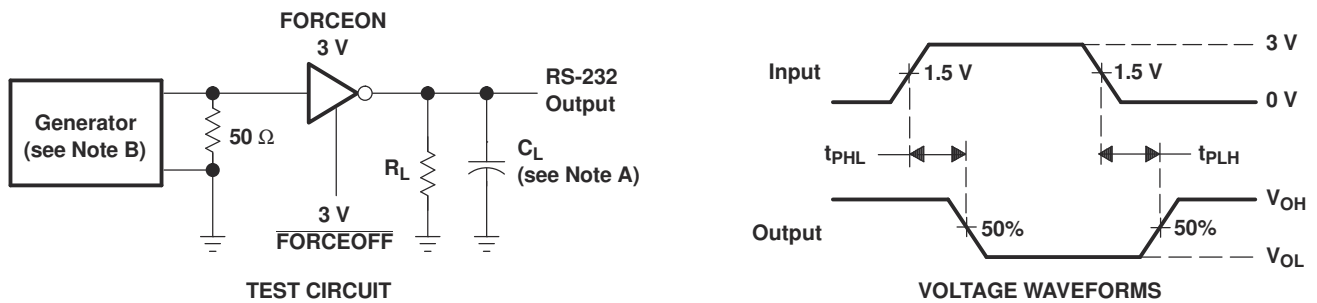
(1) All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^\circ\text{C}$.

8 Parameter Measurement Information



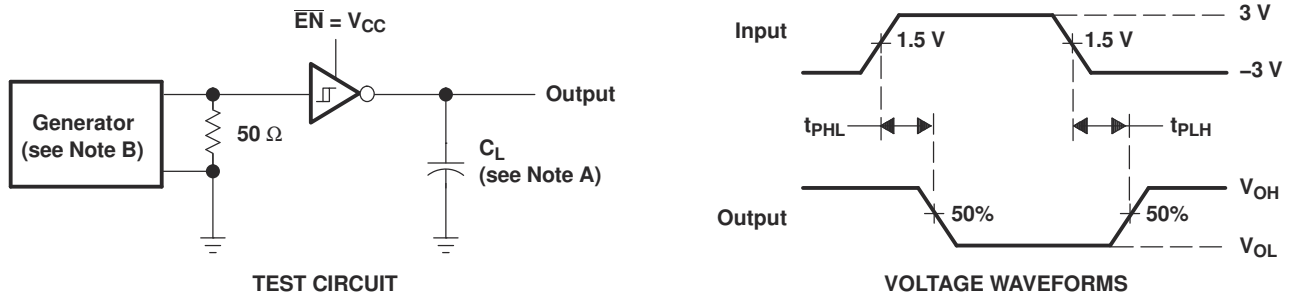
NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

8-1. Driver Slew Rate



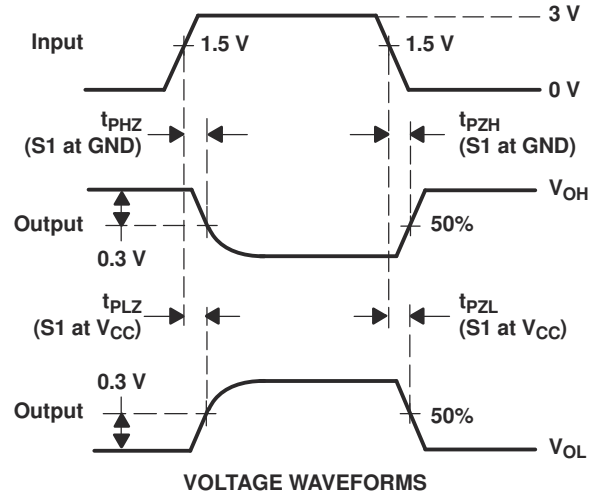
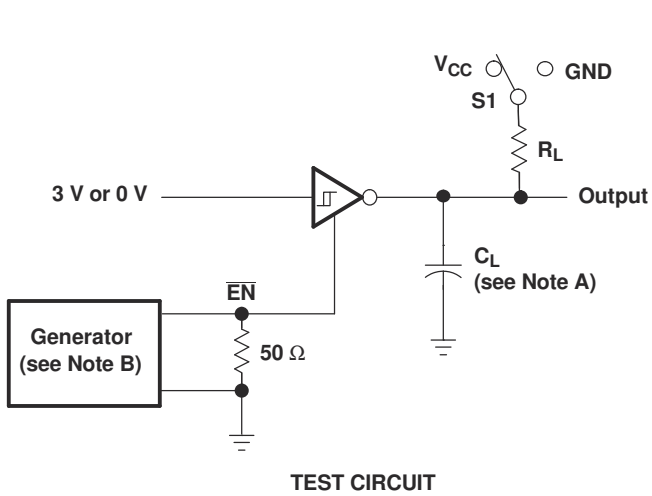
NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

8-2. Driver Pulse Skew



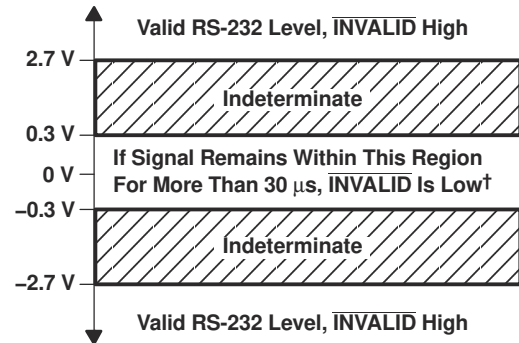
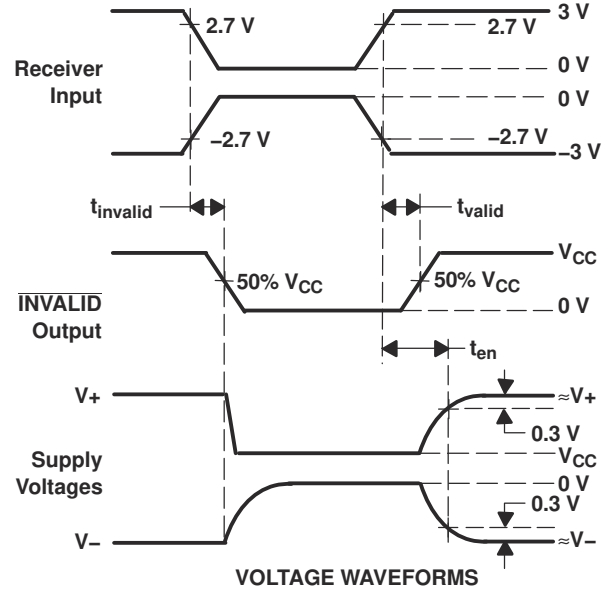
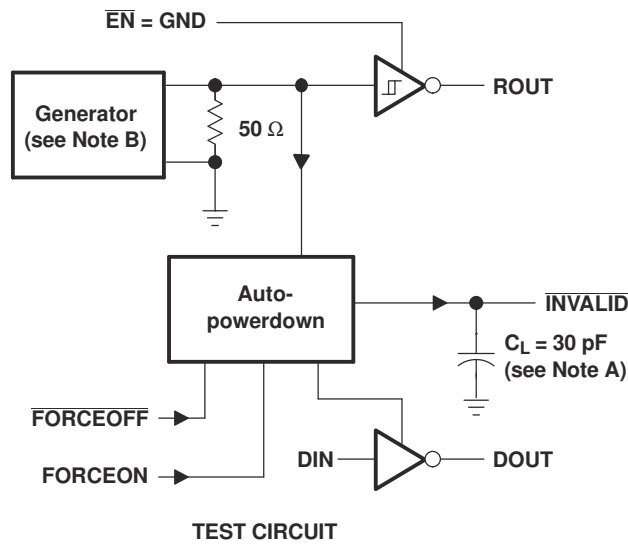
NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

8-3. Receiver Propagation Delay Times



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_r \leq 10 \text{ ns}$, $t_f \leq 10 \text{ ns}$.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

8-4. Receiver Enable and Disable Times



† Auto-powerdown disables drivers and reduces supply current to 1 μ A.

NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

8-5. $\overline{\text{INVALID}}$ Propagation Delay Times and Driver Enabling Time

9 Detailed Description

9.1 Device Functional Modes

表 9-1. Each Driver

INPUTS ⁽¹⁾				OUTPUT DOUT	DRIVER STATUS
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL		
X	X	L	X	Z	Powered off
L	H	H	X	H	Normal operation with auto-powerdown disabled
H	H	H	X	L	
L	L	H	Yes	H	Normal operation with auto-powerdown enabled
H	L	H	Yes	L	
L	L	H	No	Z	Powered off by auto-powerdown feature
H	L	H	No	Z	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

表 9-2. Each Receiver

INPUTS ⁽¹⁾			OUTPUT ROUT
RIN	EN	VALID RIN RS-232 LEVEL	
L	L	X	H
H	L	X	L
X	H	X	Z
Open	L	No	H

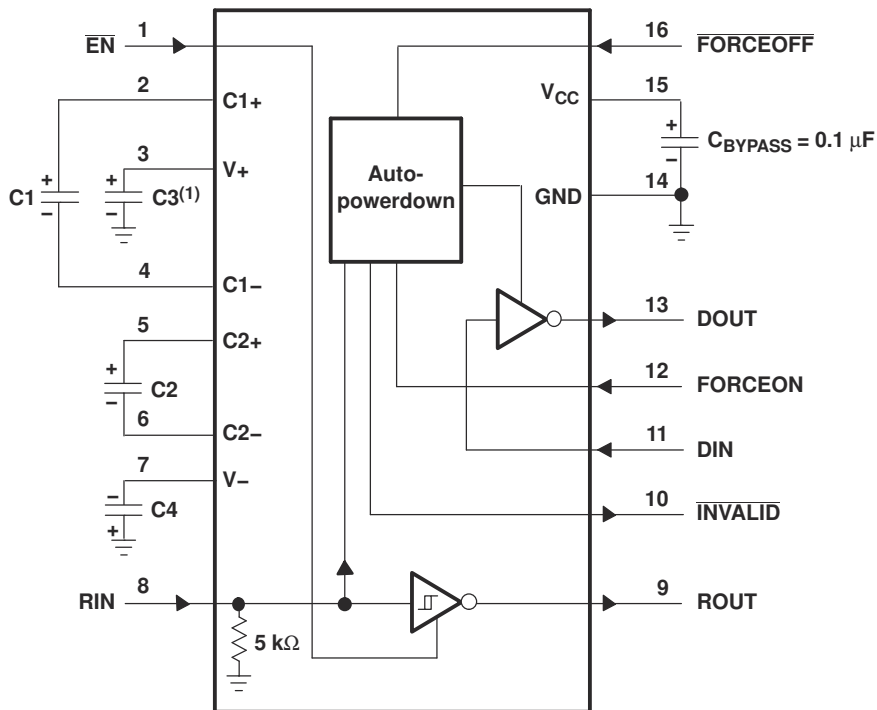
(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off

10 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

10.1 Application Information



(1) C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
3.3 V ± 0.3 V	0.1 μF	0.1 μF
5 V ± 0.5 V	0.047 μF	0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μF

 10-1. Typical Operating Circuit and Capacitor Values

11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 サポート・リソース

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11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65C3221EDB	Obsolete	Production	SSOP (DB) 16	-	-	Call TI	Call TI	-40 to 85	MU221E
SN65C3221EDBR	Active	Production	SSOP (DB) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EDBR.A	Active	Production	SSOP (DB) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EDBRG4	Active	Production	SSOP (DB) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EDBRG4.A	Active	Production	SSOP (DB) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EPWRG4	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN65C3221EPWRG4.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MU221E
SN75C3221EDB	Obsolete	Production	SSOP (DB) 16	-	-	Call TI	Call TI	0 to 70	MY221E
SN75C3221EDBR	Obsolete	Production	SSOP (DB) 16	-	-	Call TI	Call TI	0 to 70	MY221E

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C3221EDBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN65C3221EDBRG4	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN65C3221EPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65C3221EPWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C3221EDBR	SSOP	DB	16	2000	353.0	353.0	32.0
SN65C3221EDBRG4	SSOP	DB	16	2000	353.0	353.0	32.0
SN65C3221EPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN65C3221EPWRG4	TSSOP	PW	16	2000	353.0	353.0	32.0

DB0016A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



4220763/A 05/2022

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220763/A 05/2022

NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE

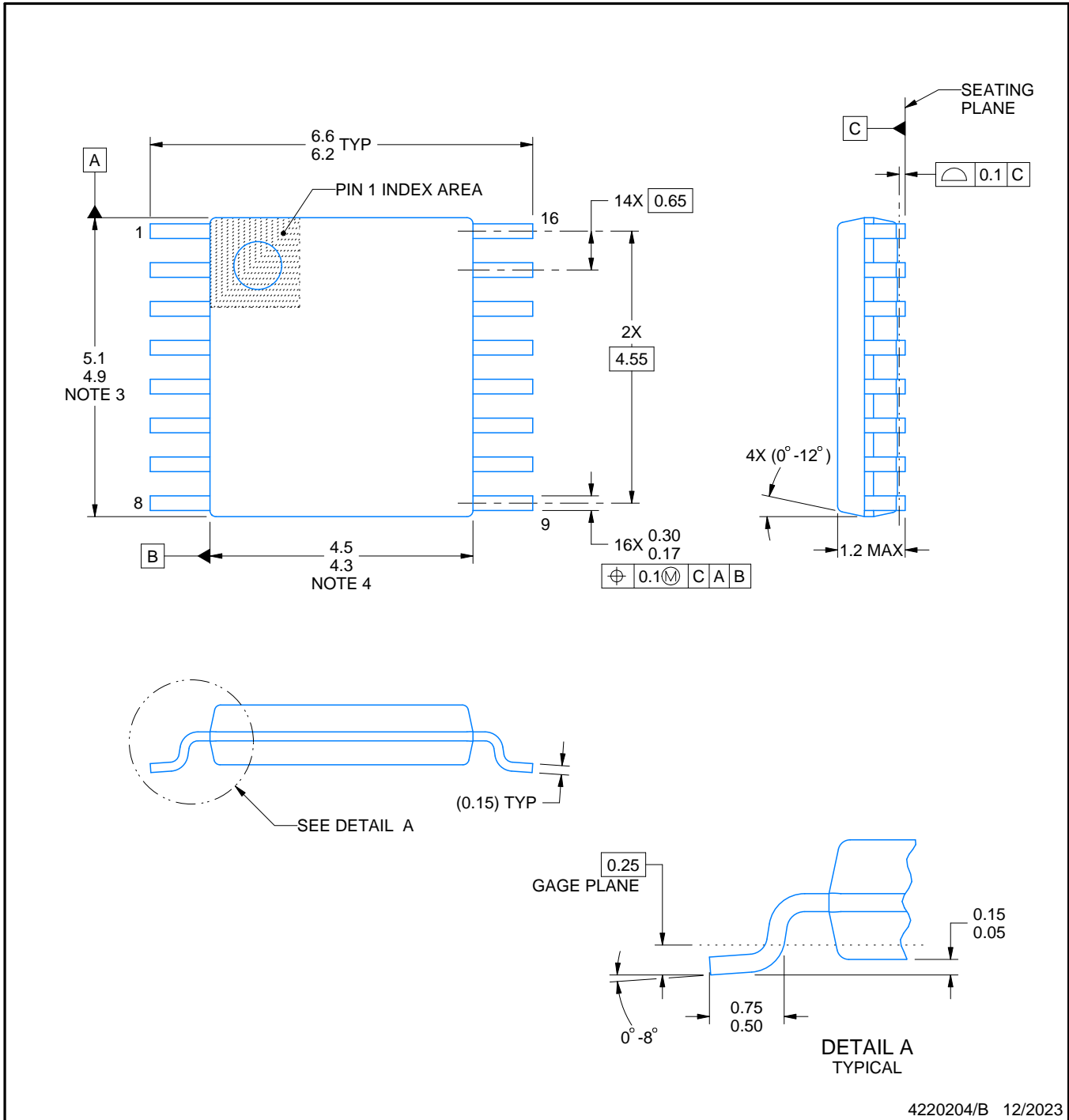
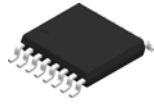


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220763/A 05/2022

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



4220204/B 12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

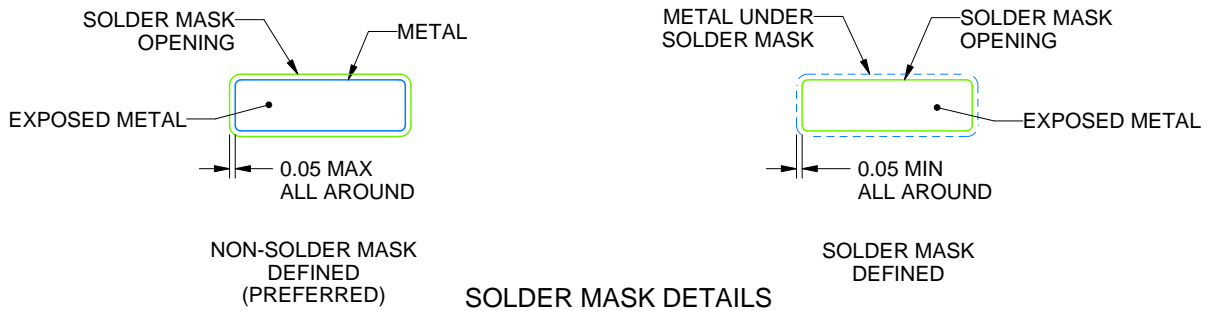
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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最終更新日：2025 年 10 月